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# CrossSim: GPU-Accelerated Simulation of Analog Neural Networks

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# Deep learning inside memory arrays

Matrix-vector  
multiplication:

$$\mathbf{Ax}$$

**Mathematical**

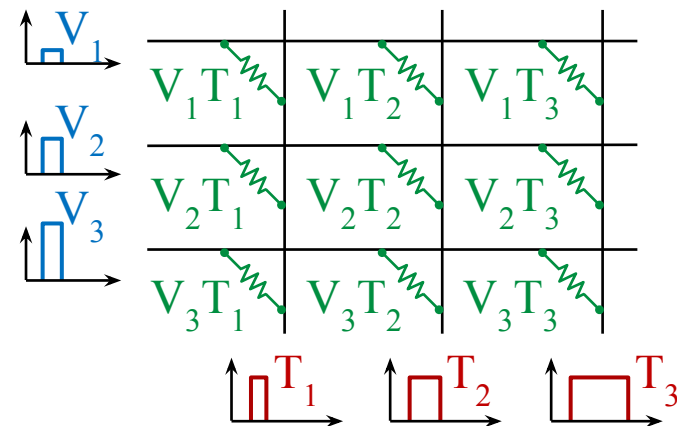
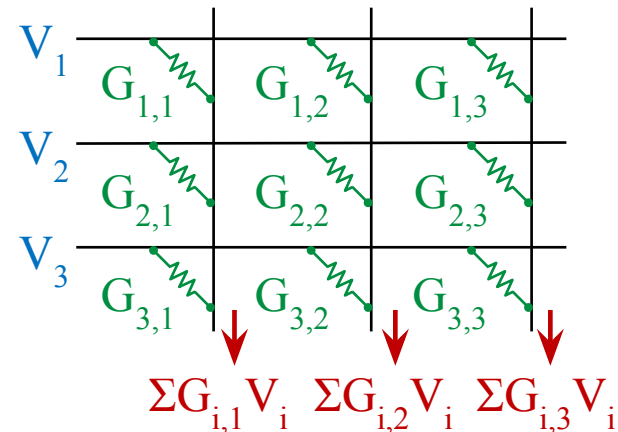
$$\begin{bmatrix} x_1 \\ x_2 \\ x_3 \end{bmatrix}^T \begin{bmatrix} A_{1,1} & A_{1,2} & A_{1,3} \\ A_{2,1} & A_{2,2} & A_{2,3} \\ A_{3,1} & A_{3,2} & A_{3,3} \end{bmatrix} = \begin{bmatrix} \sum A_{i,1} x_i & \sum A_{i,2} x_i & \sum A_{i,3} x_i \end{bmatrix}$$

Outer product  
update:

$$\mathbf{x}\delta^T$$

$$\begin{bmatrix} x_1 \\ x_2 \\ x_3 \end{bmatrix} \begin{bmatrix} x_1 \delta_1 & x_1 \delta_2 & x_1 \delta_3 \\ x_2 \delta_1 & x_2 \delta_2 & x_2 \delta_3 \\ x_3 \delta_1 & x_3 \delta_2 & x_3 \delta_3 \end{bmatrix} \otimes \begin{bmatrix} \delta_1 & \delta_2 & \delta_3 \end{bmatrix}$$

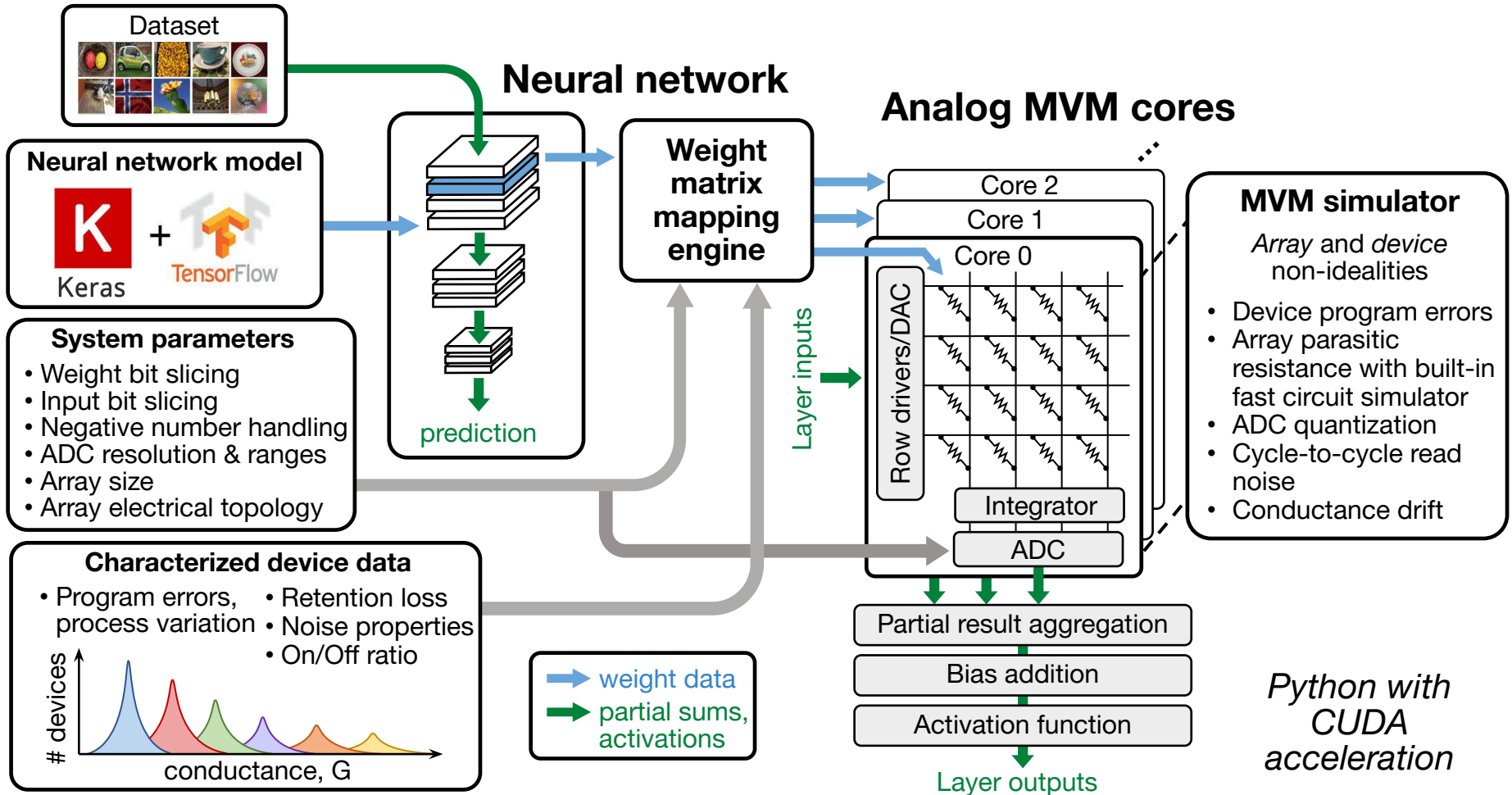
**Electrical**



Highly energy-efficient, *but is it accurate enough?*

# #ROSS SIM Inference

## Inputs to CrossSim



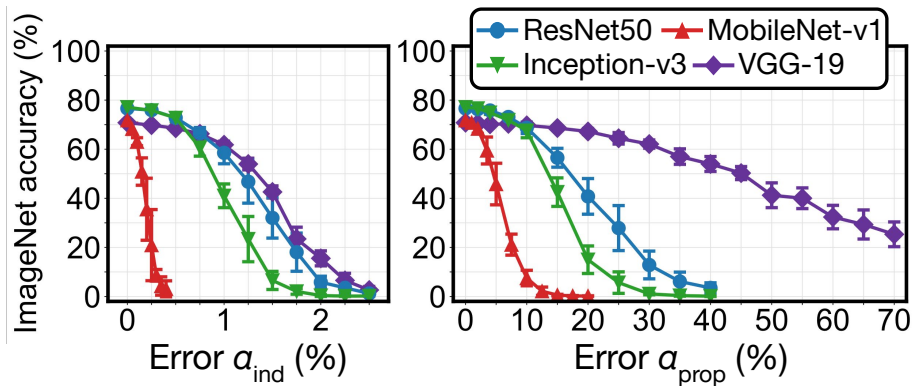
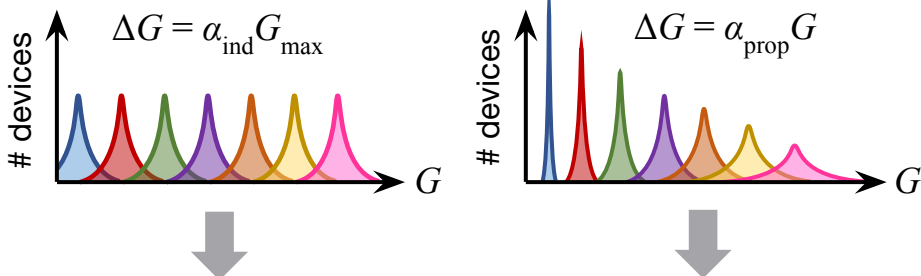
To be released soon! Check [cross-sim.sandia.gov](https://cross-sim.sandia.gov)

# Multi-scale modeling of inference accuracy

## Device properties affect accuracy

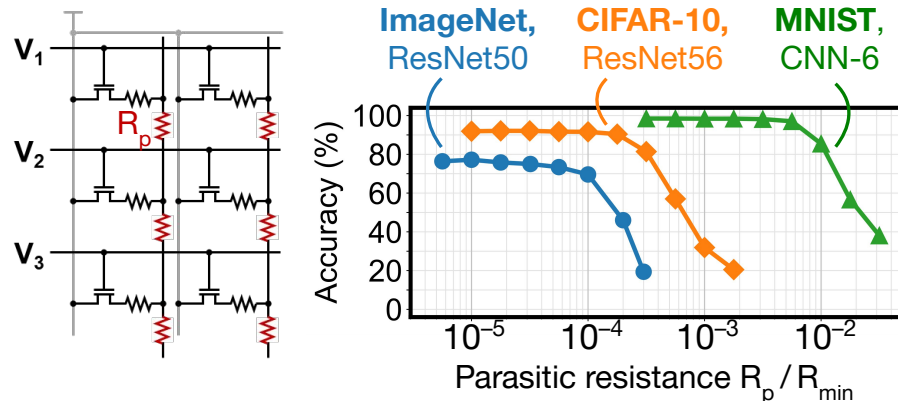
State-independent programming error

State-proportional programming error



## Array design affects accuracy

CrossSim's fast built-in circuit simulator



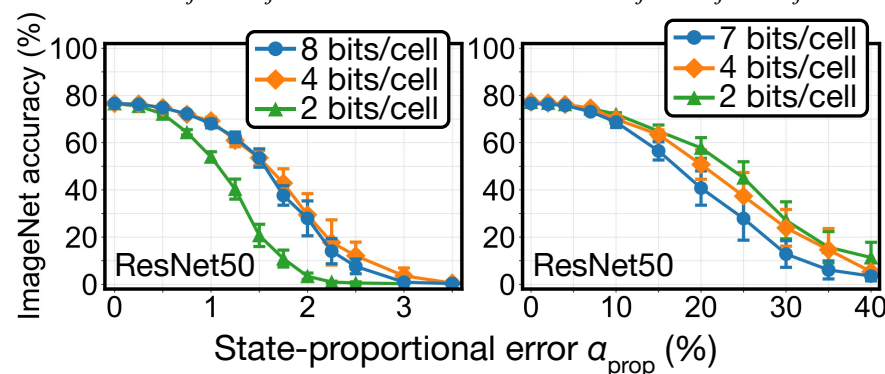
## System architecture affects accuracy

Offset subtraction

Differential cells

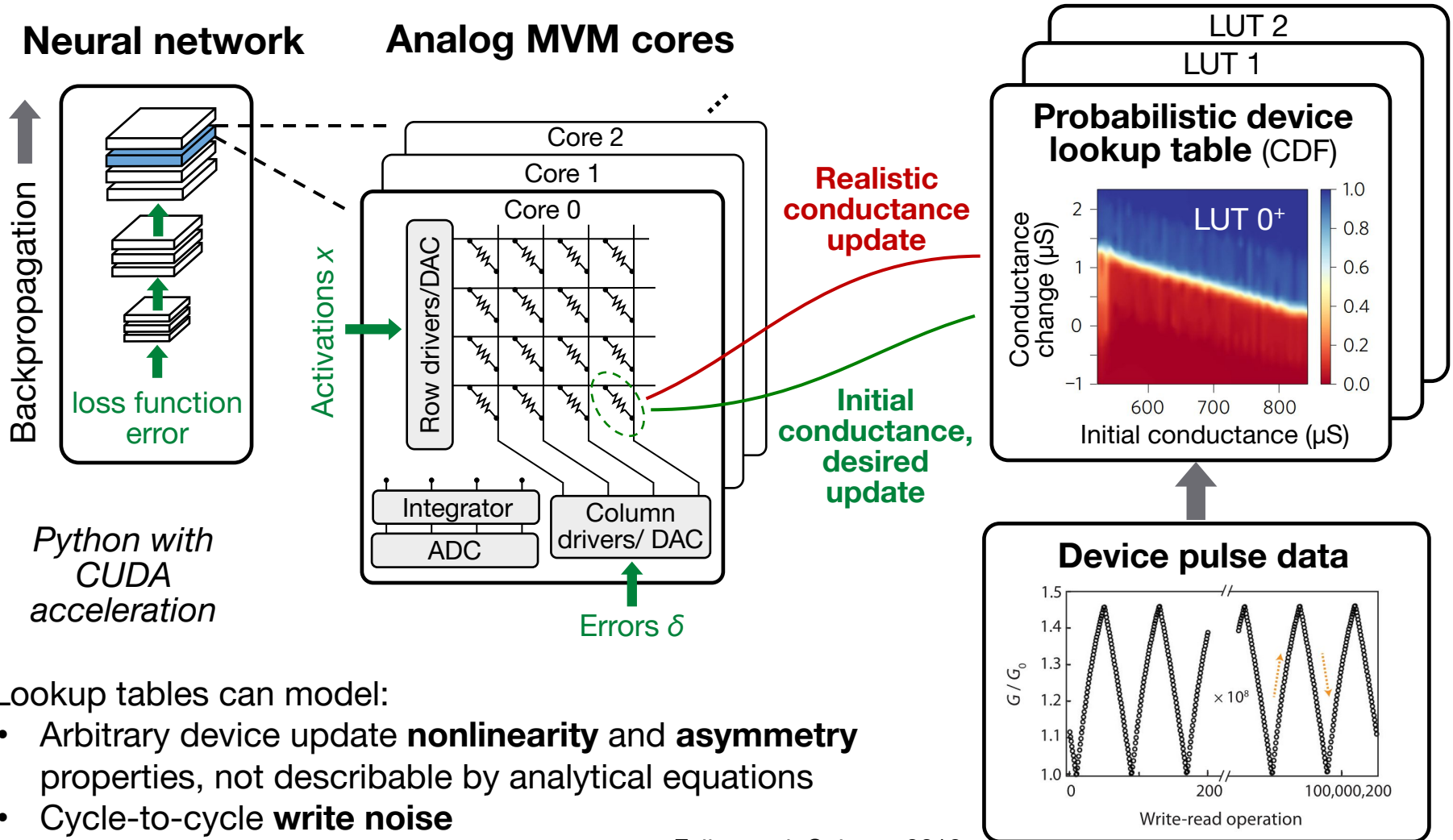
$$W_{ij} \sim G_{ij} - G_{\text{offset}}$$

$$W_{ij} \sim G_{ij}^+ - G_{ij}^-$$



Xiao et al, *arXiv:2109.01262*, 2021  
 Xiao et al, *Semi Sci Tech*, Accepted (in press), 2021

# #ROSS SIM Training



Lookup tables can model:

- Arbitrary device update **nonlinearity** and **asymmetry** properties, not describable by analytical equations
- Cycle-to-cycle **write noise**
- Device-to-device **variation**

Fuller et al, *Science* 2019  
Bennett et al, *IRPS* 2019

# From device measurements to accuracy

Device

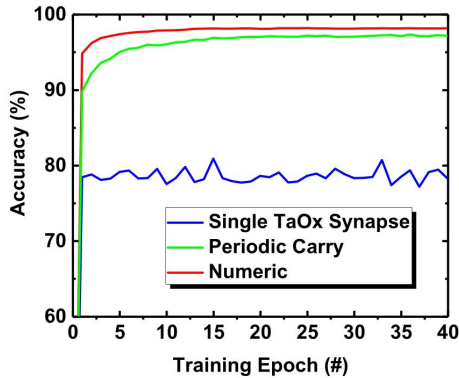
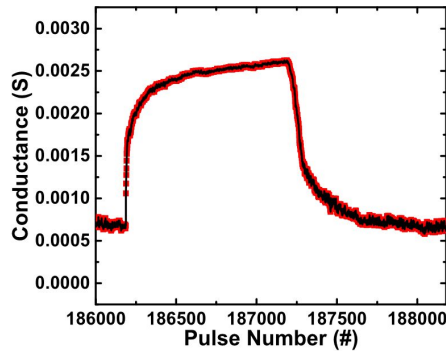
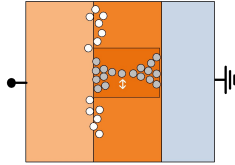


Pulse data



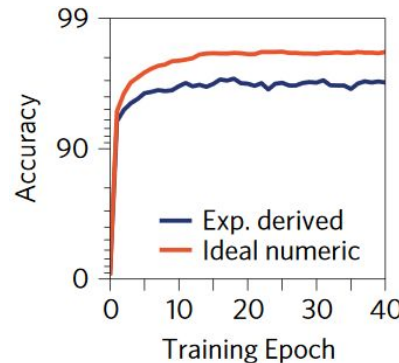
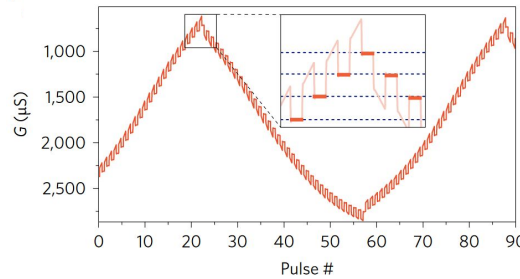
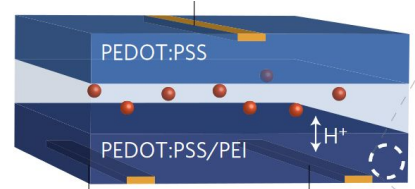
MNIST accuracy  
(2-layer MLP)

## TaO<sub>x</sub> ReRAM



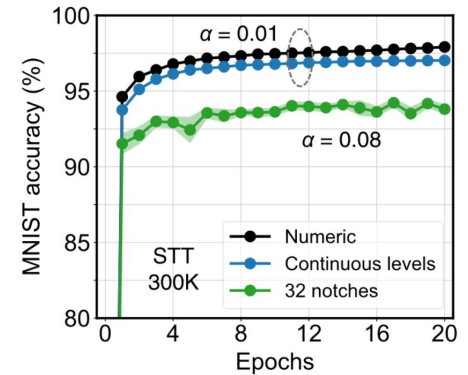
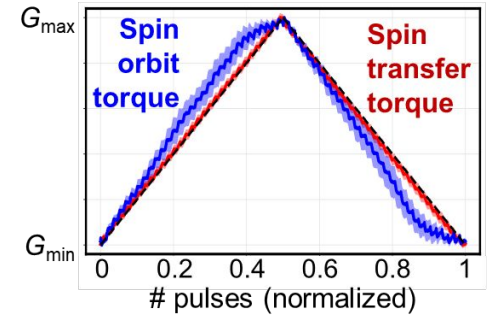
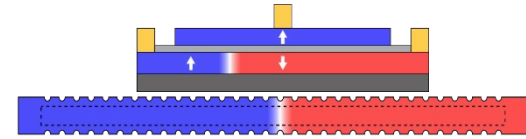
Marinella, Agarwal et al, *JETCAS* 2018

## Electrochemical RAM



Van der Burgt et al, *Nature Materials* 2017

## Domain wall magnetic tunnel junction



Liu et al, *Appl Phys Lett*, 2021